

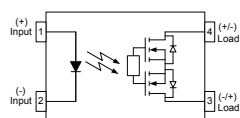
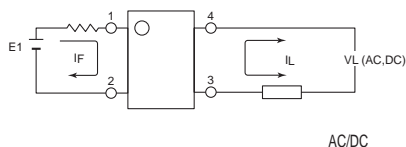
Parameter	Symbol	Rating	Units
Load Voltage	$V_L$	350	V
Load Current	$I_L$	0.13	A
On-Resistance	$R_{on}$	14	$\Omega$
I/O Breakdown Voltage	$V_{io}$	2500	Vrms



(Unit: mm)



SOP-4



1. LED Anode
2. LED Cathode
- 3.4. Drain(MOS FET)

## APSEMI PhotoRelays

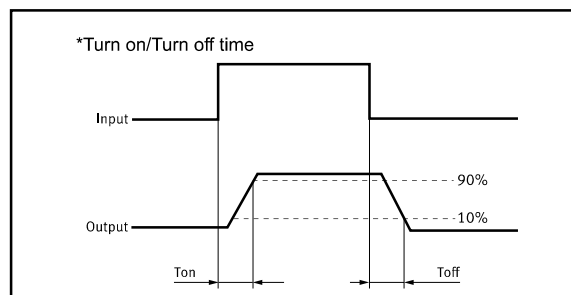
- Long life (No limit on mechanical and electrical lifetime)
- Bounce-free switching
- Higher speed and high frequency switching
- Higher sensitivity (less power consumption)
- Immunity to EMI or RFI
- No have voltaic arc, bounce, and noise More
- resistant to vibration and impact
- AC or DC load
- switching
- Small package size

## Applications

- Telecom/Datacom switching
- Multiplexers
- Meter reading systems
- Data acquisition
- Medical equipment
- Battery monitoring
- I/O Sub-Systems
- Robotics
- Aerospace
- Home/Safety security systems
- Process Control
- Energy Management
- Reed Relay EMR Replacement
- Programmable Controllers

## TPYES

Category	Output Rating		Package	Part No.	Packing Quantity
	Load Voltage	Load Current			
AC/DC	350V	0.13A	SOP-4	GAQY210S	2000pcs /reel



## Absolute Maximum Ratings (Ta = 25°C)

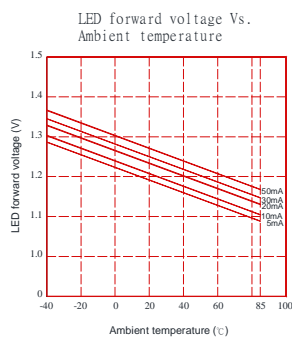
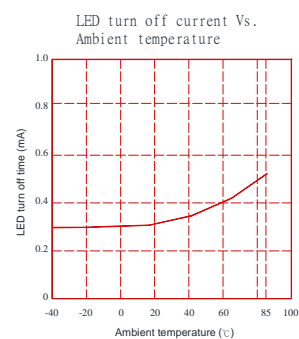
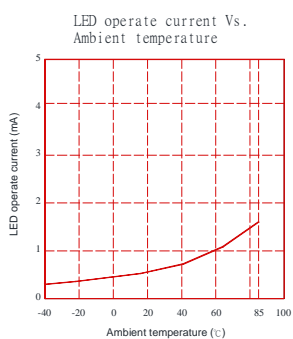
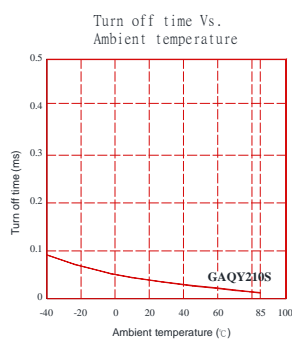
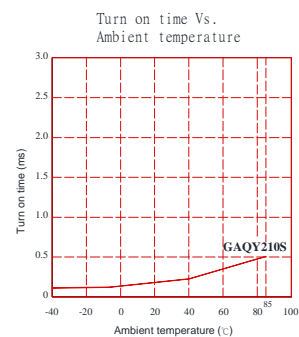
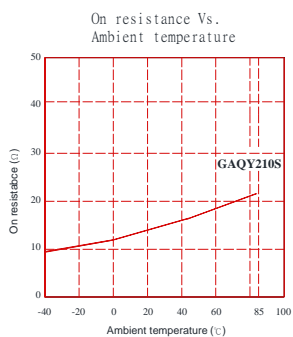
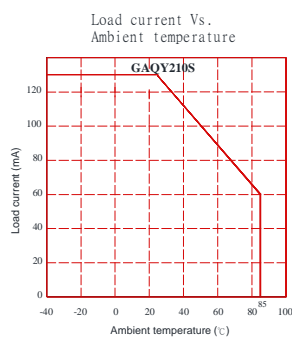
Item		Symbol	Value	Units	Note
Input	Continuous LED Current	$I_F$	50	mA	
	Peak LED Current	$I_{FP}$	1000	mA	f=100Hz, duty=1%
	LED Reverse Voltage	$V_R$	5	V	
	Input Power Dissipation	$P_{In}$	75	mW	
Output	Load Voltage	$V_L$	350	V(AC peak or DC)	
	Load Current	$I_L$	0.13	A	
	Peak Load Current	$I_{Peak}$	0.6	A	100ms(1 pulse)
	Output Power Dissipation	$P_{out}$	300	mW	
Total Power Dissipation		$P_T$	350	mW	
I/O Breakdown Voltage		$V_{I/O}$	2500	Vrms	RH=60%, 1min
Operating Temperature		$T_{opr}$	-40 to 85	°C	
Storage Temperature		$T_{stg}$	-40 to 100	°C	
Pin Soldering Temperature		$T_{sol}$	260	°C	10 sec max.

## Electrical Characteristics (Ta = 25°C)

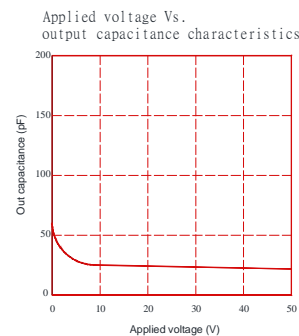
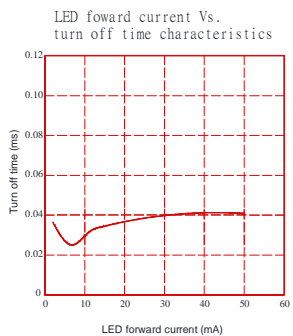
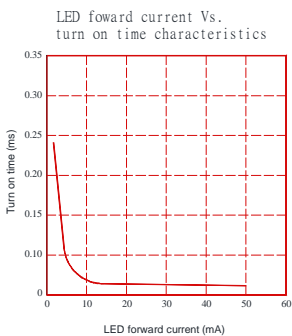
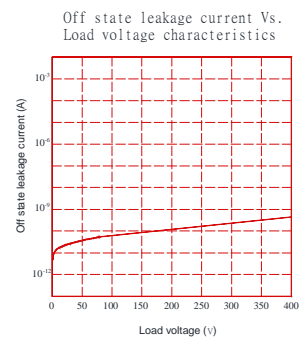
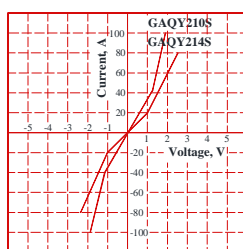
Item		Symbol	MIN.	TYP.	MAX.	Units	Conditions
Input	LED Forward Voltage	$V_F$		1.2	1.40	V	$I_F = 5\text{ mA}$
	Operation LED Current	$I_{Fon}$		0.5	2.0	mA	
	Recovery LED Current	$I_{Foff}$		0.35	0.5	mA	
	Recovery LED Voltage	$V_{Foff}$	0.7			V	
Output	On-Resistance	$R_{on}$		14	20	$\Omega$	$I_F=5\text{mA}, I_L=130\text{mA}$ , Time to flow is within 1 sec.
	Off-State Leakage Current	$I_{Leak}$		0.1		$\mu\text{A}$	$V_L=\text{Rating}$
	Output Capacitance	$C_{out}$		45		pF	$V_L=0, f=1\text{MHz}$
Transmis sion	Turn-On Time	$T_{on}$		0.08	0.15	ms	$I_F=5\text{mA}, I_L=130\text{mA}$ ,
	Turn-Off Time	$T_{off}$		0.03	0.20	ms	
Coupled	I/O Isolation Resistance	$R_{I/O}$	$10^{10}$			$\Omega$	DC500V
	I/O Capacitance	$C_{I/O}$		0.8	1.5	pF	f=1MHz

Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value):  $I_F \geq 5\text{mA}$  and  $\leq 30\text{mA}$

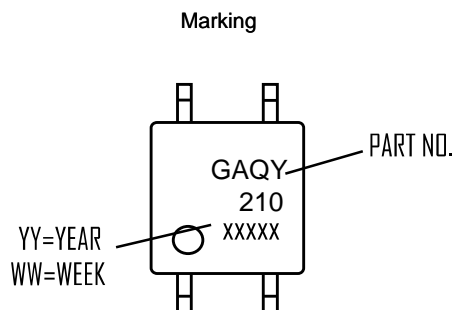
## Engineering Data



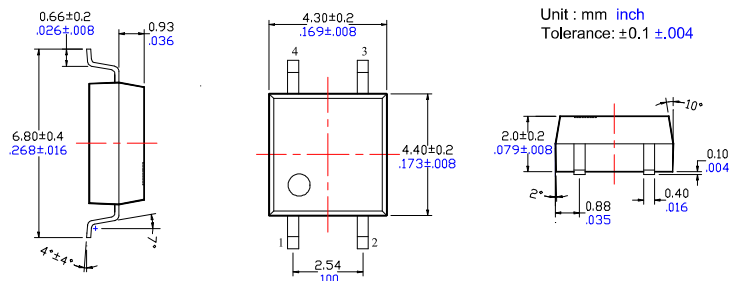
Voltage Vs. current characteristics of output at MOS portion



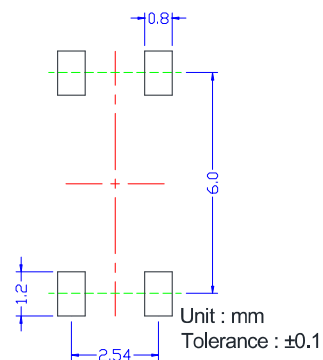
## Dimensions and Package



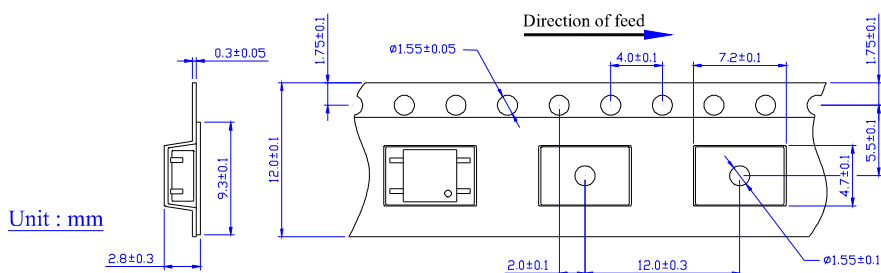
### Surface mount terminal type



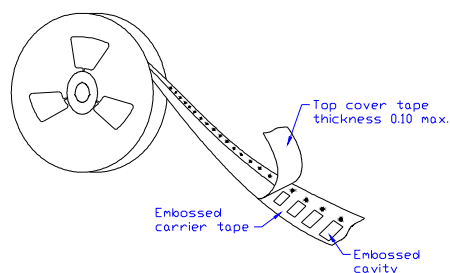
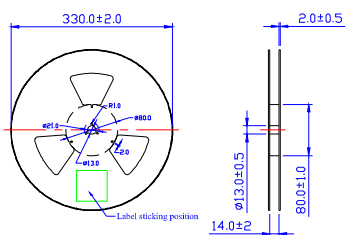
### Recommended mounting pad (Top view)



## Tape dimensions

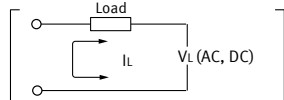
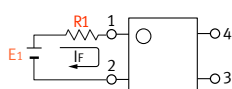


### Dimensions of tape reel



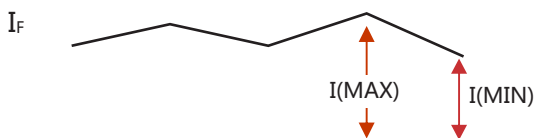
## Using Methods

Examples of resistance value to control LED forward current ( $I_F=5\text{mA}$ )



E1	R1 (Approx)
3.3V	300 $\Omega$
5.0V	600 $\Omega$
12V	1.9K $\Omega$
24V	4.1K $\Omega$

LED forward current must be more than 5mA , at  $I(\text{MIN})$  ,and less than 30mA , at  $I(\text{MAX})$ .



## Recommended Operating Conditions

Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value):

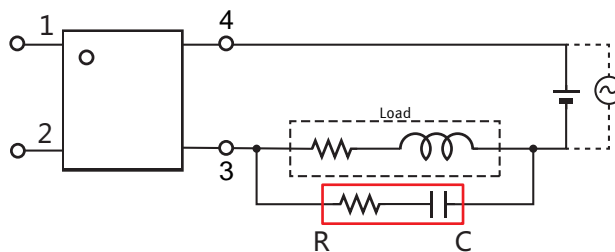
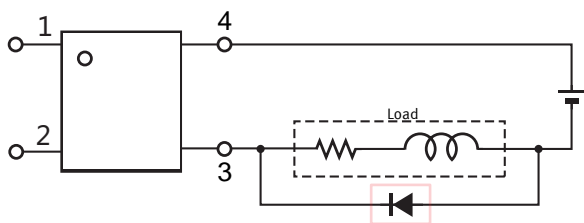
Characteristic	Symbol	Min	Typ.	Max	Unit
Forward current	$I_F$	5.0	7.0	30	mA

## Protection Circuit

Output spike voltages:if an inductive load generates spike voltages which exceed heabsolute maximum rating, the spike voltage shall be limited.

Clamp diode is connected in parallel with the load.  
Absorb capacity with external diode.

CR Snubber is connected in parallel with the load.  
Absorb capacity with buffer capacity.



When adding diodes, buffer circuits (C-R), and other protections, they need to be installed near the MOS RELAY to be effective.  
Adding protection elements may result in a slow reset time, so adjust them according to the actual situation before use.

Note: When developing designs using this product, perform the expected performance of the equipment under the operating conditions recommended by the guidelines in this document. Continuous use under heavy loads (including, but not limited to, the application of high temperatures/current/voltage and significant changes in temperature, etc.) may result in deterioration of the reliability of this product.